Technical Programme Committee

Baris Aksanli, San Diego State University, US
Mohammad Al Faruque, University of California, Irvine, US
Armin Alaghi, University of Washington, US
Luca Amaru, Synopsys, US
Paolo Amato, Micron, IT
Amir Aminifar, EPFL, CH
Lorena Anghel, Grenoble-Alpes University, FR
Giovanni Ansaloni, USI Lugano, CH
Rubio Antonio, UPC, ES
Davide Appello, STMicroelectronics, IT
Hossein Asadi, Sharif University of Technology, IR
David Atienza, EPFL, CH
Todd Austin, University of Michigan, US
Aydin Aysu, North Carolina State University, US
Nadine Azemard, LIRMM, FR
Woongki Baek, UNIST, KR
Manuel Barragan, TIMA Laboratory, FR
Ezio Bartocci, TU Wien, AT
Lejla Batina, Radboud University Nijmegen, NL
Bernd Becker, University of Freiburg, DE
Georg T. Becker, DSI Berlin, DE
Nikolaos Bellas, University of Thessaly, GR
Giovanni Beltrame, Polytechnique Montréal, CA
Mladen Berekovic, TU Braunschweig, DE
Paolo Bernardi, Politecnico di Torino, IT
Anna Bernasconi, Università di Pisa, IT
Marko Bertogna, Università di Modena e Reggio Emilia, IT
Michaela Blott, Xilinx, IE
Nicola Bombieri, Università di Verona, IT
Borzoo Bonakdarpour, Iowa State University, US
Lilian Bossuet, Université de Lyon, FR
Guillermo Botella, Complutense University of Madrid, ES
Christos Bouganis, Imperial College London, GB
David Boyle, Imperial College London, GB
Philip Brisk, University of California, Riverside, US
Andreas Burg, EPFL, CH
Andrea Calimera, Politecnico di Torino, IT
Vinicius Callegaro, Mentor a Siemens Business, US
Bertrand Cambou, Northern Arizona University, US
Kerem Camsari, Purdue University, US
Ramon Canal, Universitat Politècnica de Catalunya, ES
Luca Carloni, Columbia University, US
Benjamin Carrion Schaefer, University of Texas at Dallas, US
Luigi Carro, UFRGS, BR
Luca Cassano, Politecnico di Milano, IT
Jeronimo Castrillon, TU Dresden, DE
Mario R. Casu, Politecnico di Torino, IT
Francisco J Cazorla, BSC, ES
Wanli Chang, University of York, GB
Thidapat (Tam) Chantem, Virginia Tech, US
Anupam Chattopadhyay, Nanyang Technological University, SG
Sudipta Chattopadhyay, Singapore University of Technology and Design, SG
Ricardo Chaves, INESC-ID / Universidade de Lisboa, PT
Mingsong Chen, East China Normal University, CN
Yiran Chen, Duke University, US
Yuanqing Cheng, Beihang University, CN
Ray Cheung, City University of Hong Kong, HK
Daniel Chillet, University of Rennes 1, FR
Jungwook Choi, Hanyang University, KR
Mahesh Chowdhary, STMicroelectronics, US
Alessandro Cilardo, Università di Napoli Federico II, IT
Alessandro Cimatti, Fondazione Bruno Kessler, IT
Caroline Collange, INRIA, FR
Philippe Coussy, Université Bretagne Sud / Lab-STICC, FR
Liliana Cucu-Grosjean, INRIA, FR
Bita Darvish Rouhani, Microsoft, US
Anup Das, Drexel University, US
Eduardo de la Torre, Universidad Politécnica de Madrid, ES
Dionisio de Niz, Carnegie Mellon University, US
Flavio M. de Paula, IBM Corporation, US
Robert de Simone, INRIA, FR
Maria Merlyne De Souza, University of Sheffield, GB
Daniela De Venuto, Politecnico di Bari, IT
Alberto Antonio Del Barrio Garcia, Complutense University of Madrid, ES
Stéphanie Delaune, Université de Rennes / Inria / IRISA, FR
Alper Demir, Koc University, TR
Patricia Derler, National Instruments, US
Stefano Di Carlo, Politecnico di Torino, IT
Jean-Philippe Diguet, Lab-STICC / CNRS, FR
Rolf Drechsler, Universität Bremen / DFKI, DE
Guillaume Duc, Télécom ParisTech, FR
Günhan Dündar, Bogazici University, TR
Nikil Dutt, University of California, US
Arvind Easwaran, Nanyang Technological University, SG
Thomas Ernst, CEA-Leti, FR
Suhaib A. Fahmy, University of Warwick, GB
Ylies Falcone, Université Grenoble Alpes / Inria, FR
Deliang Fan, Arizona State University, US
Zhenman Fang, Simon Fraser University, CA
Federica Ferraguti, Università di Modena e Reggio Emilia, IT
Goerschwin Fey, Hamburg University of Technology, DE
Viktor Fischer, Hubert Curien Laboratory, Jean Monnet University, FR
Petr Fišer, Czech TU in Prague / FIT, CZ
William Fornaciari, Politecnico di Milano, IT
Nikos Foutris, University of Manchester, GB
Joseph Friedman, University of Texas at Dallas, US
Masahiro Fujita, University of Tokyo, JP
Abdoulaye Gamatie, Université de Montpellier, FR
Andreas Gerstlauer, University of Texas at Austin, US
Patrick Girard, LIRMM / CNRS, FR
Bastien Giraud, CEA-Leti, FR
Dimitris Gizopoulos, University of Athens, GR
Michael Glaß, Universität Ulm, DE
Sabine Glesner, TU Berlin, DE
Elena Gnani, Università di Bologna, IT
Dip Goswami, Eindhoven University of Technology, NL
Helmut Graeb, TU Munich, DE
Paul Gratz, Texas A&M University, US
Mariagrazia Graziano, Politecnico di Torino, IT
Daniel Grosse, Universität Bremen / DFKI, DE
radu grosu, TU Wien, AT
Jorge Guajardo, Bosch Research and Technology Center, Robert Bosch LLC, US
Ujjwal Gupta, Intel Corporation, US
Soonhoi Ha, Seoul National University, KR
Basel Halak, Southampton University, GB
Frank Hannig, Friedrich-Alexander-Universität Erlangen-Nürnberg, DE
Yuko Hara-Azumi, Tokyo Institute of Technology, JP
Jim Harkin, Ulster University, GB
Masanori Hashimoto, Osaka University, JP
Arne Heittman, RWTH Aachen University, DE
Annelie Heuser, Université de Rennes / Inria / CNRS / IRISA, FR
Gage Hills, Massachusetts Institute of Technology, US
Houman Homayoun, George Mason University, US
Martin Horauer, University of Applied Sciences Technikum Wien, AT
Shiyan Hu, Michigan Technological University, US
Yu Hua, Huazhong University of Science & Technology, CN
Mike Hutter, Cryptography Research Inc., US
Mohamed Ibrahim, Intel Corporation, US
Leandro Indrusiak, University of York, GB
Mohamad Jaber, American University of Beirut, LB
Jorn Janneck, Lund University, SE

Christophe Jego, IMS Labo, Bordeaux INP, FR
Li Jiang, Shanghai Jiao Tong University, CN
Ajay Joshi, Boston University, US
Lei Ju, School of Cyber Science and Technology, Shandong University, CN
Matthias Jung, Fraunhofer IESE, DE
Artur Jutman, Testonica Lab, EE
Maria K. Michael, Electrical and Computer Engineering & KIOS Center of Excellence / University of Cyprus, CY
Seiji Kajihara, Kyushu Institute of Technology, JP
Seokhyeong Kang, Pohang University of Science and Technology, KR
Nachiket Kapre, University of Waterloo, CA
Georgios Karakonstantis, Queen's University Belfast, GB
Naghmeh Karimi, University of Maryland, Baltimore County, US
Elif Bilge Kavun, University of Sheffield, GB
Doris Keitel-Schulz, Infineon Technologies, DE
Georgios Keramidas, Aristotle University of Thessaloniki/Think Silicon S.A., GR, GR
Oliver Keszocze, Friedrich-Alexander-Universität Erlangen-Nürnberg, DE
Hyoseung Kim, University of California, Riverside, US
Leonidas Kosmidis, BSC, ES
Tushar Krishna, Georgia Tech, US
Angeliki Kritikakou, Université de Rennes / Inria / CNRS / IRISA, FR
Bram Kruseman, NXP Semiconductors, NL
Shahar Kvatinsky, Technion, IL
Luciano Lavagno, Politecnico di Torino, IT
Kyuho Lee, UNIST, KR
Gildas Leger, Instituto de Microelectronica de Sevilla, IMSE-CNM, (CSIC - Universidad de Sevilla), ES
Romain Lemaire, CEA-Leti, FR
Guy Lemieux, University of British Columbia, CA
Kerstin Lemke-Rust, Bonn-Rhein-Sieg University of Applied Sciences, DE
Alexandre Levisse, EPFL, CH
Bing Li, TU Munich, DE
Hai (Helen) Li, Duke University / TU Munich, US
Shuangchen Li, Alibaba Group, US
Wenchao Li, Boston University, US
Mark Po-Hung Lin, National Chiao Tung University, TW
Giuseppe Lipari, Université de Lille 1, FR
Chenchen Liu, University of Maryland, Baltimore County, US
Weiqiang Liu, Nanjing University of Aeronautics and Astronautics, CN
Yongpan Liu, Tsinghua University, CN
Fabrizio Lombardi, Northeastern University, US
Marie-Minerve Louerat, CNRS / Université Pierre et Marie Curie, FR
Mohamed M. Sabry, Nanyang Technological University, SG
Alberto Macii, Politecnico di Torino, IT
Enrico Macii, Politecnico di Torino, IT
Martina Maggio, Lund University, SE
Michele Magno, ETH Zurich, CH
Frederic Mallet, Université Cote d'Azur, FR
Cristiano Malossi, IBM Research, CH
Renato Mancuso, Boston University, US
Michail Maniatakos, New York University Abu Dhabi, AE
Cedric Marchand, École Centrale de Lyon, FR
Igor L. Markov, University of Michigan, US
Ramy Medhat, University of Waterloo, CA
Julio Medina, University of Cantabria, ES
Marcel Medwed, NXP Semiconductors Austria GmbH, AT
Gokhan Memik, Northwestern University, US
Daniel Menard, INSA Rennes, FR
Nele Mentens, KU Leuven, BE
Geoff Merrett, University of Southampton, GB
Brett Meyer, McGill University, CA
Antonio Miele, Politecnico di Milano, IT
Shahriar Mirabbasi, University of British Columbia, CA
Subhasish Mitra, Stanford University, US
Tulika Mitra, National University of Singapore, SG
Anca Molnos, CEA-Leti, FR
Fernando Moraes, PUCRS University, BR
Katell Morin-Allory, TIMA Laboratory, FR
Laurent Mounier, VERIMAG / UGA, FR
Saibal Mukhopadhyay, Georgia Tech, US
Razvan Nane, TU Delft, NL
Alberto Nannarelli, TU Denmark, DK
Smail Niar, Université Polytechnique Hauts-de-France, FR
Gabriela Nicolescu, Polytechnique Montréal, CA
Michael Niemier, University of Notre Dame, US
Dimitris Nikolos, University of Patras, GR
Jean-Philippe Noel, CEA-Leti, FR
David Novo, Université de Montpellier, FR
Gianluca Palermo, Politecnico di Milano, IT
Preeti Ranjan Panda, IIT Delhi, IN
Ioannis Papaefstathiou, Aristotle University of Thessaloniki, GR
Bogdan Pasca, Intel, FR
Sudeep Pasricha, Colorado State University, US
Roberto Passerone, Università di Trento, IT
Vasilis Pavlidis, University of Manchester, GB
Li-Shiuan Peh, National University of Singapore, SG
Rodolfo Pellizzoni, University of Waterloo, CA
Miquel Pericas, Chalmers, SE
Dirk Pesch, University College Cork, IE
Linh Thi Xuan Phan, University of Pennsylvania, US
Stjepan Picek, TU Delft, NL
Christian Pilato, Politecnico di Milano, IT
Andy Pimentel, University of Amsterdam, NL
Marco Platzner, University of Paderborn, DE
Dionisios Pnevmatikatos, School of ECE, National TU Athens & FORTH-ICS, GR
Ilia Polian, University of Stuttgart, DE
Massimo Poncino, Politecnico di Torino, IT
Michele Portolan, TIMA, Univesité Grenoble Alpes, FR
Graziano Pravadelli, Universitá di Verona, IT
Davide Quaglia, Universitá di Verona, IT
Stefano Quer, Politecnico di Torino, IT
Damien Querlioz, Université Paris-Sud, FR
Anand Raghunathan, Purdue University, US
Abbas Rahimi, ETH Zurich, CH
Jaan Raik, Tallinn University of Technology, EE
Shaloo Rakheja, University of Illinois at Urbana-Champaign, US
Arijit Raychowdhury, Georgia Tech, US
Brandon Reagen, NYU/Facebook, US
Francesco Regazzoni, ALaRI, CH
semeen rehman, TU Wien, AT
Heike Riel, IBM Research, CH
Heinz Riener, EPFL, CH
Tanguy Risset, Inria/INSA-Lyon, FR
Anders Robertsson, Lund University, SE
Alberto Ros, Universidad de Murcia, ES
Tajana Rosing, University of California, San Diego, US
Davide Rossi, Universitá di Bologna, IT
Manoj Sachdev, University of Waterloo, CA
Selma Saidi, TU Dortmund, DE
Kazuo Sakiyama, University of Electro-Communications, JP
Ernesto Sanchez, Politecnico di Torino, IT
Marco D. Santambrogio, Politecnico di Milano, IT
Gilles Sassatelli, Université de Montpellier, FR
Christian Sauer, Cadence Design Systems, DE
Matteo Saveriano, University of Innsbruck, AT
Patrick Schaumont, Worcester Polytechnic Institute, US
Christoph Scholl, University of Freiburg, DE
Matthias Schunter, Intel Labs, DE
Donatella Sciuto, Politecnico di Milano, IT
Lukas Sekanina, Brno University of Technology, CZ
Olivier Sentieys, INRIA, FR
Johanna Sepúlveda, Airbus Defence and Space, DE
Rishad Shafik, Newcastle University, GB
Cristina Silvano, Politecnico di Milano, IT

L. Miguel Silveira, INESC-ID / Universidade de Lisboa, PT
Amit Kumar Singh, University of Essex, GB
Magnus Själander, Norwegian University of Science and Technology, NO
Nicolas Sklavos, University of Patras, GR
Stefan Slesazeck, NaMLab gGmbH, DE
Anna Slobodova, Centaur Technology, US
Mathias Soeken, EPFL, CH
Matteo Sonza Reorda, Politecnico di Torino, IT
Vassos Soteriou, Cyprus University of Technology, CY
Christos Sotiriou, University of Thessaly, GR
Ioannis Sourdis, Chalmers, SE
Alessio Spessot, IMEC, BE
Sebastian Steinhorst, TU Munich, DE
Sander Stuijk, Eindhoven University of Technology, NL
Ruggero Susella, STMicroelectronics, IT
Sheldon Tan, University of California, Riverside, US
Jürgen Teich, Friedrich-Alexander-Universität Erlangen-Nürnberg, DE
Vasileios Tenentes, University of Ioannina, GR
Ulrike Thomas, TU Chemnitz, DE
Daniel Tille, Infineon Technologies, DE
Lionel Torres, Université de Montpellier, FR
Martin Albrecht Trefzer, University of York, GB
Chi Ying Tsui, Hong Kong University of Science and Technology, HK
Jerzy Tyszer, Poznan University of Technology, PL
Dimitrios Tzovaras, CERTH/ITI, GR
Marco Vacca, Politecnico di Torino, IT
Rene van Leuken, TU Delft, NL
Nicolas Ventroux, CEA List, FR
Ingrid Verbauwhede, KU Leuven, BE
Marian Verhelst, KU Leuven, BE
Vincent Verneuil, NXP Semiconductors, DE
Sara Vinco, Politecnico di Torino, IT
Arnaud Virazel, LIRMM, FR
Pascal Vivet, CEA-Leti, FR
Yakir Vizel, Technion, IL
Hank Walker, Texas A&M University, US
Walter Weber, TU Wien, AT
Norbert Wehn, University of Kaiserslautern, DE
Georg Weissenbacher, TU Wien, AT
Wujie Wen, Lehigh Unversity, US
Xiaoqing Wen, Kyushu Institute of Technology, JP
Paul Whatmough, Arm Research, US
Robert Wille, Johannes Kepler University Linz, AT
Daniel Wong, University of California, Riverside, US
Stephan Wong, TU Delft, NL
Jiang Xu, Hong Kong University of Science and Technology, HK
Jason Xue, City University of Hong Kong, HK
Sotirios Xydis, National TU Athens, GR
Shigeru Yamashita, Ritsumeikan University, JP
Chengmo Yang, University of Delaware, US
Hailong Yao, Tsinghua University, CN
Yang (Cindy) Yi, Virginia Tech, US
Shouyi YIN, Tsinghua University, CN
Bei Yu, The Chinese University of Hong Kong, HK
Hao Yu, Southern University of Science and Technology, China, CN
Wenjian Yu, Tsinghua University, CN
Wei Zhang, Hong Kong University of Science and Technology, HK
Xuan (Silvia) Zhang, Washington University in St. Louis, US
Zheng Zhang, University of California, Santa Barbara, US
Zhiru Zhang, Cornell University, US
Weisheng Zhao, Beihang University, CN
Cheng Zhuo, Zhejiang University, CN
Dirk Ziegenbein, Robert Bosch GmbH, DE
Avi Ziv, IBM Research, IL
Davide Zoni, Politecnico di Milano, IT